NSN 5961-01-239-9731

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-239-9731 **Inclosure Material:** Metal **Overall Length:** 0.300 inches **Terminal Length:** 0.900 inches **Overall Diameter:** 0.180 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, instantaneous and 400.0 working peak reverse voltage **Current Rating Per Characteristic:** 70.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Precious Material And Location:** Terminal surface option gold **Test Data Document:** 82577-654295 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**